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Fabrication of $\text{In}_2\text{O}_3/\text{ZnO}@\text{Ag}$ nanowire ternary composites with enhanced visible light photocatalytic activity

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Herein, an $\text{In}_2\text{O}_3/\text{ZnO}@\text{Ag}$ ternary photocatalyst was synthesized by a facile co-precipitation process. The results indicated that Ag nanowires were encapsulated by $\text{In}_2\text{O}_3/\text{ZnO}$ compounds, and the obtained $\text{In}_2\text{O}_3/\text{ZnO}@\text{Ag}$ photocatalyst showed strong absorption in the visible light region. The photoluminescence (PL) emission intensity gradually decreased for $\text{In}_2\text{O}_3/\text{ZnO}@\text{Ag}$ as compared to that for the $\text{In}_2\text{O}_3/\text{ZnO}$ composites and pure ZnO. The as-prepared $\text{In}_2\text{O}_3/\text{ZnO}@\text{Ag}$ composites exhibited excellent visible light photocatalytic activities for degradation of organic contaminants (methyl orange and 4-nitrophenol). The enhancement of photocatalytic activity was ascribed to the extended visible light absorption region by Ag nanowires and the formation of close hetero-structure by the matched band structures of In_2O_3 and ZnO. Finally, a possible photocatalytic mechanism was proposed based on the matched energy band structure and active species trapping experiments.

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1. Introduction

In recent years, environmental pollution and energy shortage have created serious social and economic issues for the economic development of modern human society.^{1–3} Semiconductor-based photocatalysis has been widely employed as a highly efficient technique to overcome these issues.^{4–6} Zinc oxide (ZnO), as a promising photocatalyst, has attracted widespread interests owing to its outstanding electrical and optical properties, low-cost, high biological safety, versatile shapes and structures, environmental friendliness, and strong photocatalytic degradation ability of organic pollutants under UV light.^{7–10} However, pure ZnO materials show poor absorption of visible light; this limits the efficient utilization of solar energy. Another main drawback of ZnO is the rapid recombination of photo-induced electron–hole pairs that results in low quantum yield for any photocatalytic reaction.^{11–13} Therefore, extension of the absorption edge of ZnO to the visible light region for the utilization of about 43% solar spectrum while suppressing the recombination of photo-generated electron–hole pairs is still a great challenge for scientists. In the past few years, various modification strategies, including sensitization, semiconductor coupling, doping and noble metal deposition, have been employed to activate ZnO photocatalysis under visible light.^{14–17} Among these, the most

effective strategy is coupling ZnO with a narrow band-gap semiconductor with matched band potential, which has been proven to be a feasible approach. Considering that the band gap of In_2O_3 ($E_g = 2.8$ eV) is lower than that of ZnO ($E_g = 3.2$ eV) and its valence and conduction band alignments are staggered relative to those of ZnO, a type II heterojunction can be formed by coupling them together.^{18–21} The formation of type II hetero-structures has been recognized as an attractive route to overcome the limitations of ZnO because it promotes efficient charge separation, enlarges the effective contact interfaces, and improves the optical absorption.^{22,23}

In the binary system, the relatively narrow region of visible light response and relatively lower separation efficiency of electron–hole pairs limit its practical applications. Ternary system construction composites have been extensively investigated *via* introduction of an additional constituent, such as Ag, Au, carbon, and graphene oxide (GO), to the binary heterojunction.^{24–29} Ternary system construction not only changes the nature of charge transfer but also broadens the region of light absorption. For instance, a $\text{Cu}_x\text{O}/\text{ZnO}@\text{Au}$ heterojunction exhibits improved photocurrent generation and higher photocatalytic activity as compared to its binary counterpart $\text{Cu}_x\text{O}/\text{ZnO}$ due to the addition of Au. Through decorating Au on the surface of a $\text{Cu}_x\text{O}/\text{ZnO}$ composite, a fluent electron transfer from Cu_xO to ZnO and eventually to Au can be achieved, whereas the photo-induced holes remain in the conduction bands of Cu_xO ; this can lead to multistep charge transfer.³⁰ Hierarchical $\text{Ag}/\text{AgBr}/\text{TiO}_2$ composites with porous structures have been fabricated and displayed enhanced visible light photocatalytic activities,³¹ in which AgBr as the main active component generates electron–hole pairs. The Ag

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nanoparticles act not only as an active component generating energetic electrons by surface plasmon resonance (SPR) under the irradiation of visible light, but also as an electron-transfer media to enhance the stability of the photocatalyst. Wu *et al.* fabricated porous-structured Ag/ZnO/ZnFe₂O₄ ternary composites *via* a facile calcination process.²⁵ The synthesized ternary composites show significantly enhanced photocatalytic activity towards the degradation of an organic dye as compared to the binary counterpart ZnO/ZnFe₂O₄. The Ag/AgCl/Ag₂O heterostructure composites with enhanced photocatalytic activities for the degradation of Ciprofloxacin have been successfully synthesized; it has been demonstrated that Ag can be integrated into a Z-scheme photocatalytic system and acts as an excellent electron transfer mediator to enhance the oxidizing and reducing powers for photocatalysis.³² Other ternary component hybrid examples have been intensively investigated, in which a metal acts as the electron-transfer mediator or as an SPR source to enhance visible light absorbance and promote efficient charge separation.^{23,33–35}

Herein, we report the preparation of an In₂O₃/ZnO@Ag ternary component photocatalyst, with enhanced visible light photocatalytic activity, *via* a facile co-precipitation process. The microstructure, phase, and optical properties of the samples have been investigated. The visible light photocatalytic activities of the as-prepared composites are investigated *via* degradation of MO or 4-NP. As expected, the as-obtained In₂O₃/ZnO@Ag ternary component exhibited excellent charge separation efficiency and visible light photocatalytic performance. Finally, the charge transfer and probable photocatalytic mechanism have been discussed and proposed on the basis of optical characterization, band gap structure, and reactive species reaction.

2. Experimental details

2.1 Formation of the In₂O₃/ZnO@Ag ternary heterojunction photocatalyst

Ag nanowires were fabricated by a classical polyol process.¹³ The purified Ag nanowires were mixed into 1 mmol L⁻¹ ethanol for the fabrication of In₂O₃/ZnO@Ag ternary composites. First, 0.18 mmol ZnAc and 0.06 mmol In(NO₃)₃ were added to deionized water and thoroughly mixed under stirring until a uniform mixed solution was formed. Then, 10 ml of Ag suspension and 8 ml of TEA were added in sequence to the abovementioned solution. The mixed solution was heated *via* a water-bath method at 90 °C for 2 h. The obtained precipitates were centrifuged, washed several times with deionized water and ethanol, and dried in an oven at 60 °C. The final In₂O₃/ZnO@Ag composites were thus obtained *via* annealing at 200 °C for 1 h. For comparison, In₂O₃/ZnO and Ag/ZnO composites were also prepared under the same condition without the addition of Ag nanowires and In(NO₃)₃. The In₂O₃/ZnO/Ag mixture was fabricated by ball milling pure In₂O₃, ZnO, and Ag.

2.2 Characterization

The crystal structures were studied by powder X-ray diffraction (XRD). The morphologies and microstructures of the obtained

samples were measured by field emission scanning electron microscopy (FESEM; JSM-6700F, Japan) and high resolution transmission electron microscopy (FE-SEM SUPRA™ 40). Chemical states of the samples were analyzed using X-ray photoelectron spectroscopy (XPS; PHI-5300, ESCA, USA). The UV-vis diffused reflectance spectra (UV-vis DRS) of the samples were obtained using a UV-3600 spectrophotometer. Photoluminescence (PL; Renishaw1000, UK) spectra were obtained at room temperature using a He–Cd laser as the excitation light source at 325 nm.

The photocatalytic activities of the as-prepared samples were evaluated by the photocatalytic degradation of methyl orange (MO) and 4-nitrophenol (4-NP). First, 10 mg of the as-prepared In₂O₃/ZnO@Ag photocatalyst was ultrasonically dispersed in 50 ml of 10 mg L⁻¹ MO or 10 ml of 1 mg L⁻¹ 4-NP aqueous solution in a quartz glass container; the mixture was magnetically stirred for 30 minutes in the dark. Then, visible light irradiation was carried out using a 300 W Xe lamp with an optical cut-off filter ($\lambda \geq 420$ nm) as the light source. At given intervals, 3 ml aliquots were sampled and analyzed by obtaining variations in the absorption band (464 nm and 317 nm) in the UV-vis spectra of MO or 4-NP, respectively.

2.3 Photoelectrochemical characterization

The photoelectrochemical experiments, including photocurrent, electrochemical impedance spectroscopy (EIS), and linear sweep voltammetry (LSV) measurements were carried out using an electrochemical workstation (CHI-660C, Chenhua Instrument, China). A Pt wire and Ag/AgCl electrode were used as the counter electrode and reference electrode, respectively. The working electrodes were prepared as follows: 0.2 g of the obtained photocatalyst was mixed with 0.1 g of polyethylene glycol and 3 ml of water; then, the mixture was ground to form a slurry. Next, the slurry was coated onto a pre-cleaned 1 cm × 1 cm FTO glass electrode, dried, and calcined at 450 °C for 30 min in an oven. A 300 W Xe lamp with an optical cut-off filter ($\lambda \geq 420$ nm) was used as the excitation light source. A Na₂SO₄ aqueous solution (0.1 M) was used as the electrolyte. EIS measurements were carried out in a 0.1 M Na₂SO₄ solution at an open circuit potential over a frequency range from 10⁵ to 10⁻¹ Hz. LSV measurements plots of the samples were obtained at a scan rate of 100 mV s⁻¹.

3. Result and discussion

3.1 Structural characterization

The phase composition and crystal properties of the as-prepared samples were analyzed by X-ray diffraction (XRD), as shown in Fig. 1. It was found that the pure ZnO sample had sharp peaks at 31.8°, 34.4°, 36.3°, 47.6°, 56.7°, 62.9°, 68.0°, and 69.2°. The positions of all the peaks can be indexed to the wurtzite ZnO structure (JCPDS File no. 36-1451) and correspond to (100), (002), (101), (102), (110), (103), (112) and (201). For the obtained In₂O₃/ZnO heterojunction, there are four new sharp diffraction peaks at the 2 θ values of 30.1°, 35.5°, 51.1°, and 60.7°, which can be indexed to the (222), (400), (440), and (622)



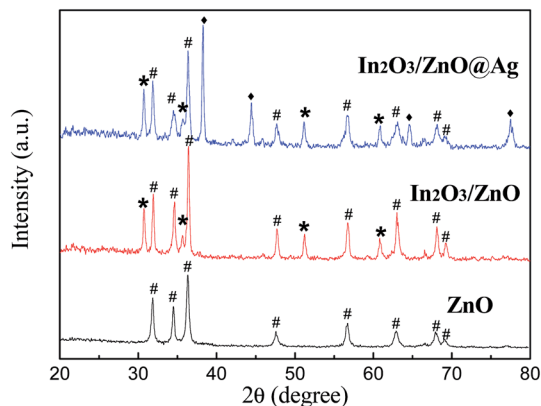


Fig. 1 XRD patterns of pure ZnO, $\text{In}_2\text{O}_3/\text{ZnO}$ heterojunction, and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composites (#: ZnO; *: In_2O_3 ; ◆: Ag).

crystal planes of the body-centered cubic structure of In_2O_3 (JCPDS 71-2194), respectively. For the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ sample, three new characteristic peaks related to the face-centered-cubic (fcc) metallic Ag (JCPDS 04-0783) (111), (200), and (220) planes are observed in the diffraction pattern, and other two sets of diffraction peaks indexed to orthorhombic In_2O_3 and wurtzite ZnO do not change; this reveals that the introduction of Ag nanowires does not change the crystal phase and crystallinity of In_2O_3 and ZnO.

The microscopic morphologies and structures of the $\text{In}_2\text{O}_3/\text{ZnO}$ and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites were investigated using FESEM. Fig. 2(a and b) present the SEM images of the obtained $\text{In}_2\text{O}_3/\text{ZnO}$ heterojunction. It can be clearly observed that ZnO presents a hexagonal disk-structure with an average diameter of

200 nm and a thickness of about 40 nm; small and uniform In_2O_3 nanoparticles are highly dispersed on the surface of the ZnO disks. The In_2O_3 nanoparticles have a size distribution of about 20–40 nm. Similarly, Fig. 2(c and d) show the surface morphology of the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composites; it can be found that the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composites present rod-like shapes, with well-dispersed $\text{In}_2\text{O}_3/\text{ZnO}$ nanoparticles coated on the surface of the Ag nanowires.

Fig. 3(a) shows a low-magnification TEM image of an $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite. Under the TEM observation, a dark nanowire with a diameter of about 120 nm can be observed in the center, which is consistent with the diameter of Ag nanowires. The thickness of the shell encapsulated by the ZnO/ In_2O_3 composites is 150–200 nm. In_2O_3 nanoparticles with a diameter of 20 nm are dispersed on the surface of the ZnO nanodisks, as seen from Fig. 3(b).

In the HRTEM image of Fig. 3(c), a clear and sharp interface further confirms that ZnO and In_2O_3 are in intimate contact, which is beneficial for transfer of charge at the interface. The measured lattice spacings of 0.248 nm and 0.715 nm for the crystalline planes correspond well to the (002) plane of hexagonal wurtzite ZnO and the (110) crystalline plane of the body-centered cubic structured In_2O_3 , respectively.^{36,37} The good crystalline quality and the sharp interface between ZnO and In_2O_3 are beneficial for the separation of the photo-generated carriers. The elemental mappings of Zn, In, O, and Ag are shown in Fig. 3(d–g). It can be found that the Zn, In, and O elements are concomitant and have uniform distribution in the micro-rod; this further indicates that ZnO and In_2O_3 are nested within each other. However, the size of the Ag element distribution is narrow; this confirms that Ag is distributed as a bearing core coated with

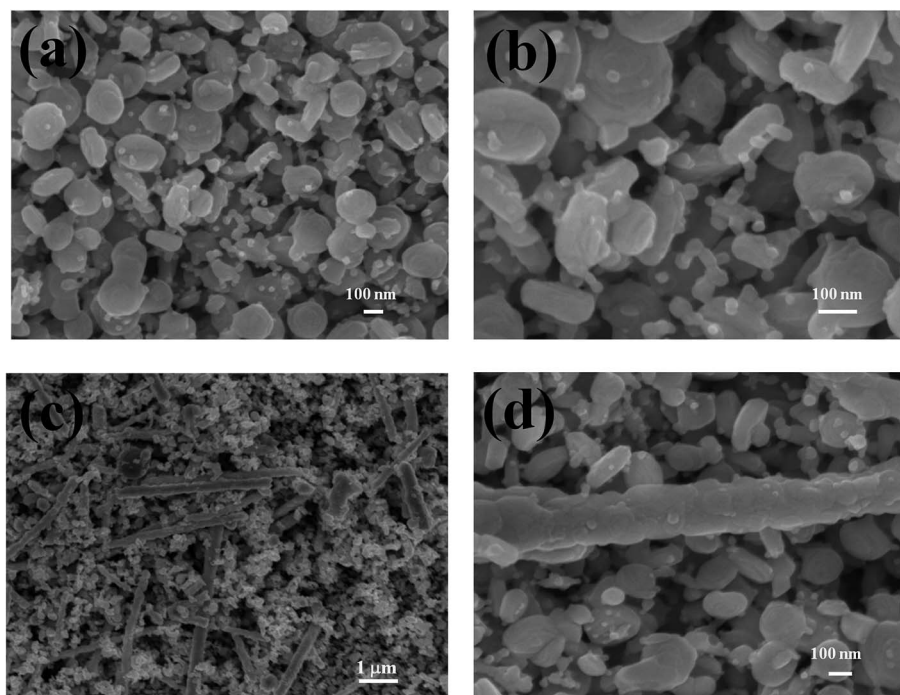


Fig. 2 SEM images of the $\text{In}_2\text{O}_3/\text{ZnO}$ (a and b) and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite (c and d).



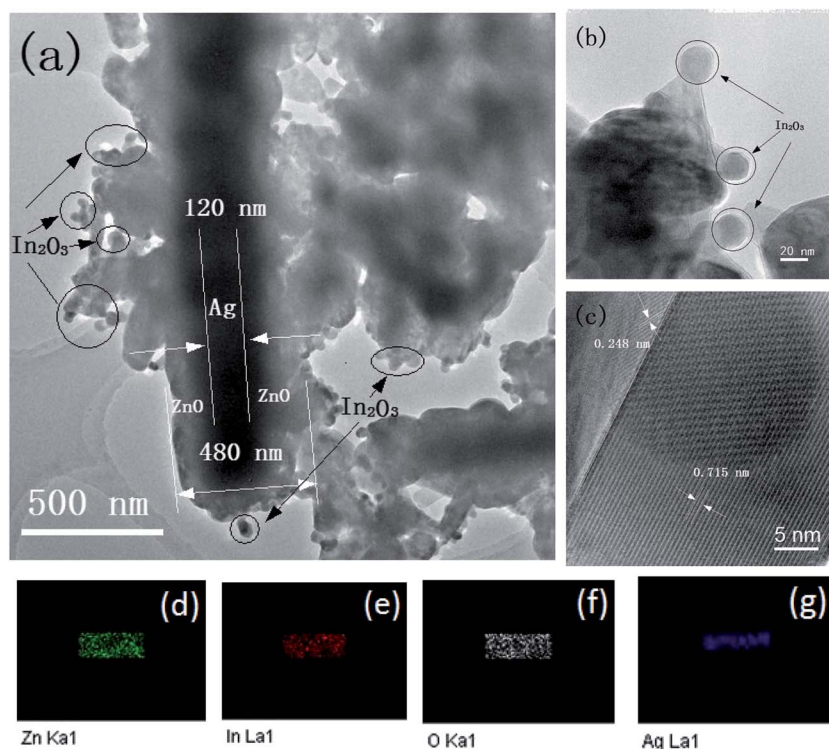


Fig. 3 (a and b) TEM image, (c) HRTEM image, and (d–g) Zn, In, O, and Ag elemental mappings of an individual $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composite.

peripherally distributed Zn, O, and In. Based on the above-mentioned results, it is verified that Ag nanowires are successfully encapsulated by the $\text{In}_2\text{O}_3/\text{ZnO}$ nanoparticles.

To verify the existence of ZnO, In_2O_3 , and the chemical states of the Ag species, the X-ray photoelectron spectrum (XPS) of $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ was obtained (Fig. 4). The XPS spectrum of Zn

2p for the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites (Fig. 4(a)) has two major peaks centered at 1044.2 and 1021.4 eV, which are assigned to Zn 2p_{1/2} and Zn 2p_{3/2}, respectively, indicating the Zn(II) oxidation state in ZnO.^{25,38} On comparing the peak positions of Zn 2p for pure ZnO and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites, it can be found that the peak positions of Zn 2p shift to higher binding energies

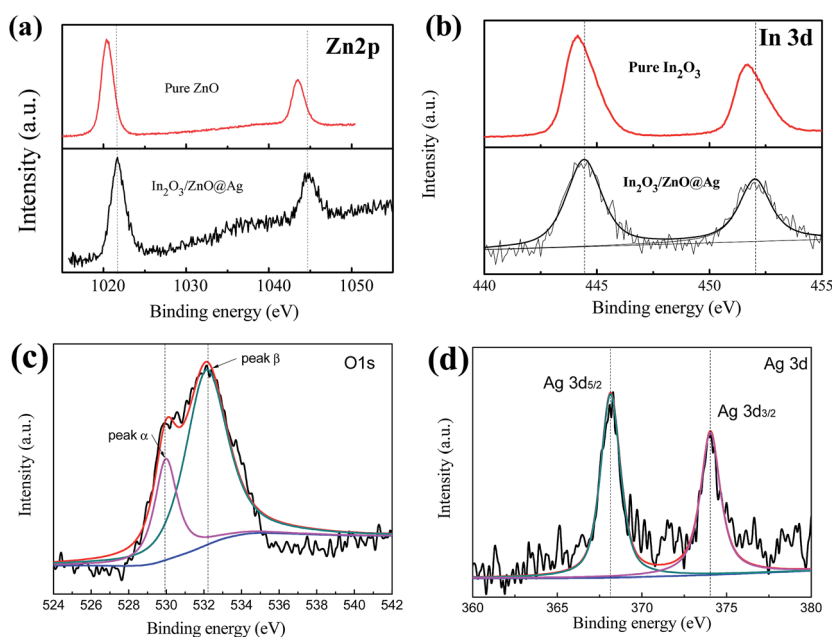


Fig. 4 High-resolution XPS curves of the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites for the elements: (a) Zn 2p, (b) In 3d, (c) O 1s, and (d) Ag 3d.



when compared with those of pure ZnO. In terms of the In 3d spectrum (Fig. 4(b)), there are two characteristic peaks centered at 444.16 and 451.73 eV that can be attributed to In 3d_{5/2} and In 3d_{3/2}, respectively, which indicate the presence of In³⁺ in the ZnO/In₂O₃ composites.³⁹ It can be found that the In 3d peak positions of the samples were shifted to higher values when compared with that of pure In₂O₃. The slight shift in the binding energies of Zn 2p and In 3d can be ascribed to a shift of the Fermi energy level of ZnO and In₂O₃, which is caused by the strong interaction between ZnO, In₂O₃, and Ag in the composites. In the O 1s XPS spectrum (Fig. 4(c)), the asymmetric profile can be divided into two symmetrical peaks centered at 530.05 eV and 532.22 eV. The peak located at 530.05 eV is assigned to the lattice oxygen binding with In and Zn (denoted as In–O and Zn–O). In addition, the peak centered at 532.22 eV is associated with the surface-absorbed oxygen species.^{26,40} The surface oxygen species can produce primary active superoxide radicals and hydroxyl radicals, which are capable to trap photo-induced electrons and holes. Thus, the surface-absorbed oxygen species are very important for photocatalysis.²⁵ From Fig. 4(d), it can be seen that two peaks centered at 368.1 eV and 374.1 eV are ascribed to Ag 3d_{5/2} and Ag 3d_{3/2} of metallic Ag⁰ species, respectively, which confirm the existence of Ag NWs in the composites.⁴¹

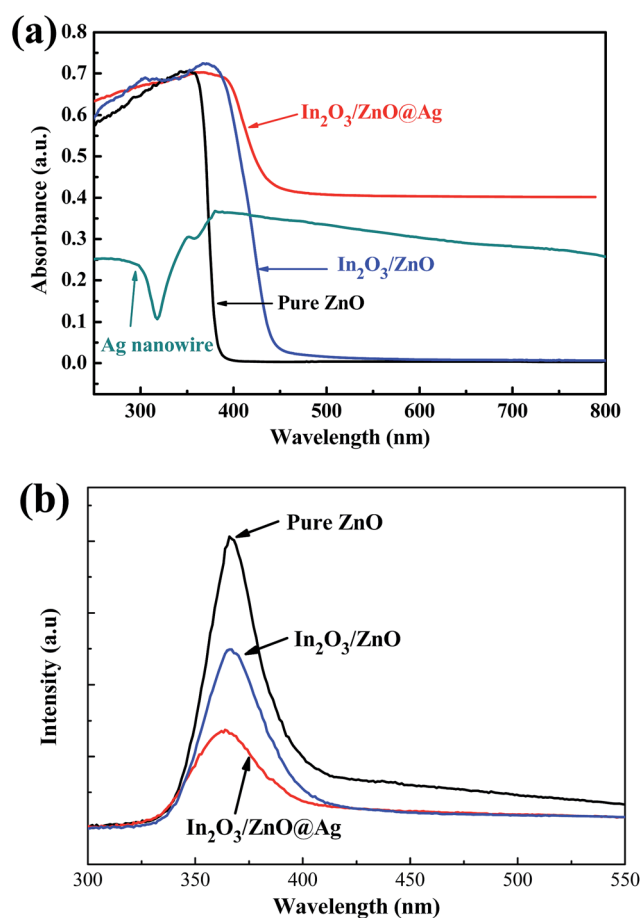


Fig. 5 UV-vis absorption (a) and photoluminescence (b) spectra of the pure ZnO, In₂O₃/ZnO, and In₂O₃/ZnO@Ag composite.

Fig. 5(a) shows the UV-vis absorption spectra of the bare ZnO, Ag nanowires, In₂O₃/ZnO, and In₂O₃/ZnO@Ag composites. The ZnO nanodisks exhibit intense optical absorption in the UV region, and a steep absorption edge is located at around 380 nm.³⁰ The as-prepared In₂O₃/ZnO heterojunctions exhibit a significant enhancement in the light absorption intensity and an obvious red-shift of the absorption edge to the visible light region, which is due to the addition of In₂O₃. The SPR peaks of silver nanowires occur at 350 and 380 nm. The maximal peak at 380 nm corresponds to the transverse plasmon resonance of the nanowires, and the weaker peak appearing at 350 nm is attributable to the quadrupole resonance excitation of the nanowires.⁴² In addition, the strength of the absorption after 380 nm slightly decreases, with a long tail over the wavelength range from 380 nm to 800 nm. While for ternary In₂O₃/ZnO@Ag composite, the widest visible light absorption was achieved, indicating that there was a synergistic effect between ZnO, In₂O₃, and Ag. That is to say, In₂O₃/ZnO@Ag ternary composites could efficiently utilize visible light and produce more photo-generated carriers, resulting in higher photocatalytic activity.

To investigate the photocatalytic mechanism, PL spectroscopy measurements for pure ZnO, In₂O₃/ZnO heterojunction, and In₂O₃/ZnO@Ag ternary composite were conducted, and the results are shown in Fig. 5(b). Compared with pure ZnO, binary In₂O₃/ZnO composites exhibit a significant PL quenching that implies that the recombination rates of the photo-generated electron-hole pairs in the samples have been restrained. In particular, the In₂O₃/ZnO@Ag ternary sample displays lowest PL intensity; this indicates that for the In₂O₃/ZnO@Ag ternary sample, the photo-induced electron-hole pairs possess highest transfer efficiency than that for other samples. That is to say, Ag nanowire-modified In₂O₃/ZnO structures possess highest ability to separate the photo-generated electron-hole pairs that would boost the photocatalytic reaction.^{24,43}

The photocurrent transient response is an available method to evaluate the separation efficiency and recombination rate of photo-induced electron-hole pairs in the composite photocatalysts. In general, a higher photocurrent implies higher electrons-hole separation efficiency, thus leading to higher photocatalytic activity. The photocurrent transient responses of ZnO, In₂O₃/ZnO, and In₂O₃/ZnO@Ag ternary composite samples under visible light were measured and are shown in Fig. 6(a). Notably, the photocurrent value of In₂O₃/ZnO@Ag ternary composite is several times higher than that of pristine ZnO and In₂O₃/ZnO, which implies that the In₂O₃/ZnO@Ag composite has a higher separation rate of photo-generated electron-hole pairs under the irradiation of visible light.^{44,45} To further explore the separation of photo-induced electron-hole pairs and transport of interfacial electron, the electrochemical impedance spectroscopy (EIS) was conducted for these samples, and the results are shown in Fig. 6(b). It can be observed that the impedance arc radius of the In₂O₃/ZnO@Ag ternary composite is much smaller than that of the pure ZnO and In₂O₃/ZnO hybrids; this indicates that the In₂O₃/ZnO@Ag ternary composites possess lowest electron transfer resistance and best interfacial electron transfer performance.⁴⁶ The LSV plots of the samples were also measured, as shown in Fig. 6(c).



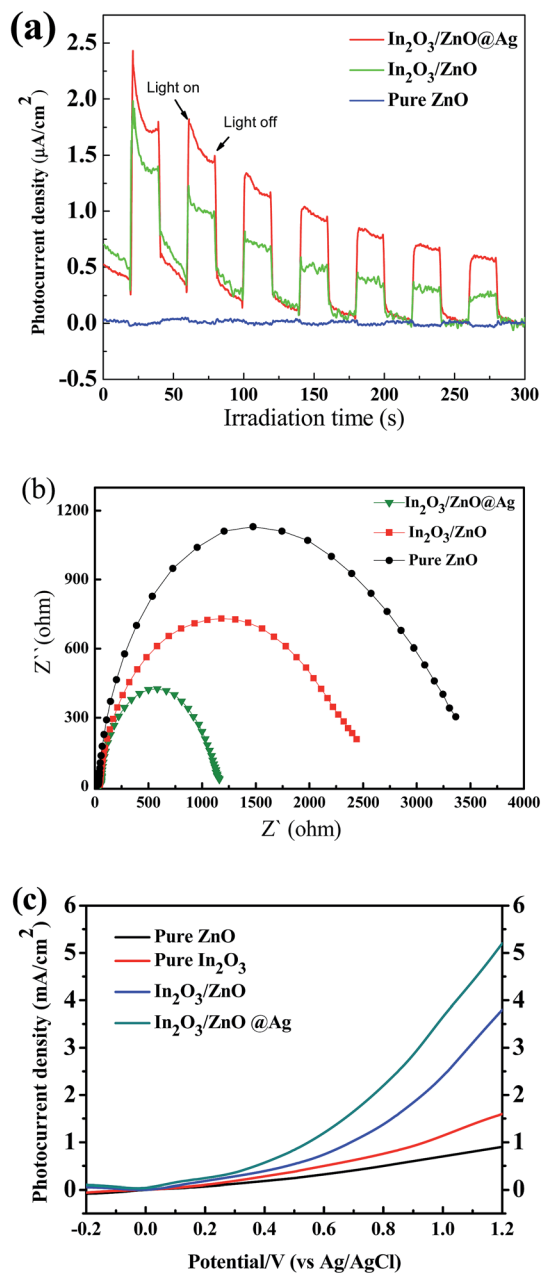


Fig. 6 The photocurrent responses profiles (a), Nyquist plots of electrochemical impedance spectra (b), and linear sweep voltammetry (c) for pure ZnO, $\text{In}_2\text{O}_3/\text{ZnO}$, and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite.

The photocurrent density of bare ZnO and In_2O_3 film was 0.92, and 1.63 mA cm^{-2} at 1.2 V (vs. Ag/AgCl). The bare ZnO film exhibited the least photocurrent response due to its wide bandgap. Under the same condition, the ZnO/ In_2O_3 film showed higher photocurrent at 3.82 mA cm^{-2} , and the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite film exhibited the highest photocurrent density of 5.27 mA cm^{-2} at 0.6 V (vs. Ag/AgCl). This suggests that $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ exhibited stronger ability for the separation of photo-generated electron-hole pairs than bare ZnO, In_2O_3 , and ZnO/ In_2O_3 , which can be ascribed to the enhancement of visible light absorption capacity and the formation of a heterojunction between ZnO, In_2O_3 , and Ag.^{47,48}

3.2 Photocatalytic activity and stability

The photocatalytic activities of bare ZnO, $\text{In}_2\text{O}_3/\text{ZnO}$, and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite were evaluated in terms of the degradations of MO and 4-NP under visible light irradiation. As illustrated in Fig. 7, self-degradation of MO and 4-NP is negligible without the addition of photocatalysts; this indicates that these two types of organic dyes are photochemically stable. As shown in Fig. 7(a), $\text{In}_2\text{O}_3/\text{ZnO}$ and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ show evidently enhanced photocatalytic activity as compared to pure ZnO for the degradations of MO. For comparison, Ag/ZnO and $\text{In}_2\text{O}_3/\text{ZnO}/Ag$ mixtures were used as reference catalysts. After visible light irradiation for 90 min, only 10% MO is degraded over ZnO, indicating that ZnO presents poor visible light photocatalytic activity for the degradation of MO, ascribed to the wide band gap of ZnO. The degradation rates of MO over Ag/ZnO and $\text{In}_2\text{O}_3/\text{ZnO}$ reached 43% and 67%, respectively. Ag/ZnO present enhanced photocatalytic activity when compared with ZnO, which can be attributed to the Ag SPR effect.^{9,15} For $\text{In}_2\text{O}_3/\text{ZnO}$, the enhanced photocatalytic activity can be ascribed to the formation of a type II heterojunction between In_2O_3 and ZnO.¹⁰ Furthermore, when Ag is introduced into the $\text{In}_2\text{O}_3/\text{ZnO}$ composites, the fabricated $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composites show highest degradation efficiency. The corresponding rate constants k determined for different catalysts are obtained by fitting the gradient of the graph of $\ln(C_0/C)$ versus time, and the results are shown in Fig. 7(b). The obtained rate constants k are 0.0027 min^{-1} , 0.0091 min^{-1} , 0.0174 min^{-1} , 0.0184 min^{-1} , and 0.031 min^{-1} for ZnO, Ag/ZnO, $\text{In}_2\text{O}_3/\text{ZnO}$, $\text{In}_2\text{O}_3/\text{ZnO}/Ag$ mixture, and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$, respectively. The k value of $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ is about twice that of $\text{In}_2\text{O}_3/\text{ZnO}$, 3.5 times that of Ag/ZnO, and 11 times that of ZnO.

Fig. 7(c) shows the photocatalytic activities of pure ZnO, ZnO/ In_2O_3 , and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composites for the degradation of 4-NP. After visible light irradiation for 240 min, pure ZnO materials show very low degradation efficiencies for 4-NP; however, degradation efficiencies for 4-NP significantly increase to 40%, 44%, 68%, and 92% for Ag/ZnO, $\text{In}_2\text{O}_3/\text{ZnO}/Ag$ mixture, ZnO/ In_2O_3 , and $\text{In}_2\text{O}_3/\text{ZnO}@Ag$, respectively. $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ shows the best catalytic effect for the degradation of 4-NP. The k values are determined to be 0.0003, 0.0018, 0.0028, 0.0043, and 0.0099 min^{-1} (as shown in Fig. 7(d)). The photocatalytic performance ranking of these composites for the degradation of MO and 4-NP is same as follows: $\text{In}_2\text{O}_3/\text{ZnO}@Ag > \text{ZnO}/\text{In}_2\text{O}_3 > \text{In}_2\text{O}_3/\text{ZnO}/Ag \text{ mixture} > Ag/\text{ZnO} > \text{ZnO}$. This suggests that introduction of Ag into ZnO/ In_2O_3 composites may improve the separation of photo-generated electron-hole pairs, which is beneficial to enhance the photocatalytic performance.

As the photo-stability of a photocatalyst is very important for its practical applications, cyclic photocatalytic degradation experiments were carried out to investigate the photo-stability of $\text{In}_2\text{O}_3/\text{ZnO}@Ag$. As displayed in Fig. 7(e and f), the degradation rates of MO and 4-NP show only a little decrease after three cycles. Excluding the loss of the photocatalyst in the cycling tests, $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ can be considered as a stable photocatalyst.



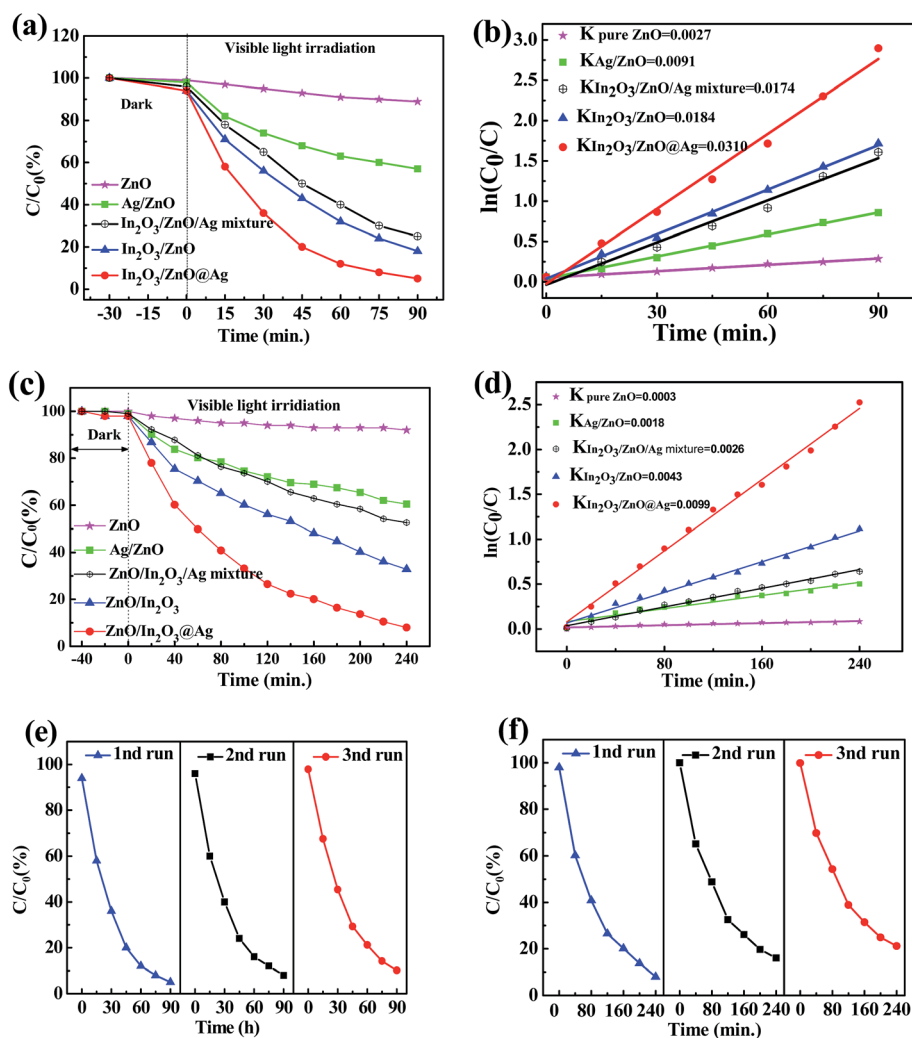


Fig. 7 Degradation profiles and kinetic linear simulation curves of MO (a and b) and 4-NP (c and d) photocatalytic degradation with pure ZnO, Ag/ZnO, In₂O₃/ZnO, In₂O₃/ZnO/Ag mixture, and In₂O₃/ZnO@Ag composites. Photocatalytic stability of the In₂O₃/ZnO@Ag ternary composites for MO (e) and 4-NP (f) degradation with three cycles of use.

3.3 Proposed photocatalytic mechanism

As is well-known, it is important to investigate the active species in the photocatalytic process to better understand the mechanism of photocatalysis. The photocatalytic degradation of dyes mainly involves several active radical species such as hole (h^+), superoxide anion radical ($\cdot O_2^-$), and hydroxyl radicals ($\cdot OH$).^{18,27} To distinguish the roles of the reactive species, a series of scavengers is employed during the photodegradation processes. Benzoquinone (BQ), ammonium oxalate (AO), and *tert*-butanol (*t*-BuOH) are used as scavengers for $\cdot O_2^-$, photogenerated holes, and $\cdot OH$ in degradation of MO, respectively. As shown in Fig. 8, with 1 mmol of *tert*-butyl alcohol (*t*-BuOH) as an $\cdot OH$ scavenger added to the solution, the degradation rate of MO over the In₂O₃/ZnO@Ag ternary composites sample has no obvious decrease, implying that $\cdot OH$ radical species plays a relatively minor role in the reaction system. However, photocatalytic activity of the In₂O₃/ZnO@Ag ternary composite is greatly suppressed by the addition of BQ or AO, suggesting that both

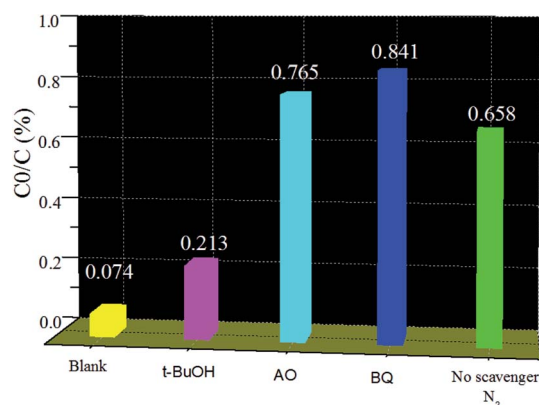


Fig. 8 Trapping experiment of active species during the photocatalytic degradation of MO over In₂O₃/ZnO@Ag under visible light irradiation.



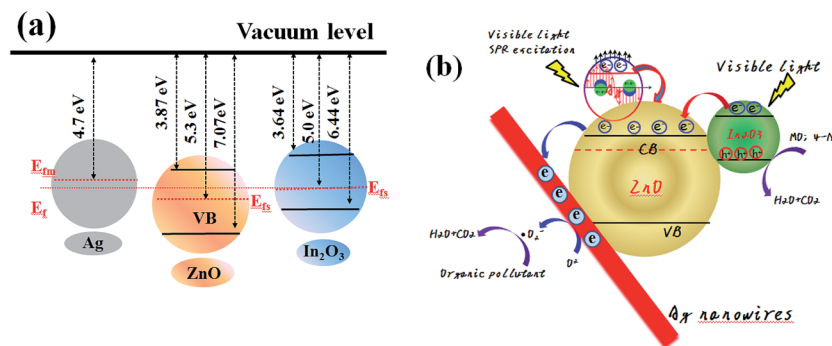


Fig. 9 Schematic showing the energy band structure (a) and electron–hole pair separation in the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites (b).

photo-generated $\cdot\text{O}_2^-$ and holes are the main oxidative species and play crucial roles in the degradation process of MO. To further confirm the role of $\cdot\text{O}_2^-$ radical species, a N_2 purging experiment was conducted and its results were compared with those obtained under air-equilibrated conditions. The photocatalytic efficiency of the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite is obviously suppressed under a N_2 atmosphere (N_2 as the O_2 scavenger). The results imply that dissolved oxygen can act as an electron scavenger to give $\cdot\text{O}_2^-$ radical species during the photocatalytic reaction. Consequently, it can be further confirmed that the photocatalytic degradation of MO over the as-prepared $\text{ZnO}/\text{In}_2\text{O}_3@Ag$ composite is mainly governed by $\cdot\text{O}_2^-$ and h^+ rather than $\cdot\text{OH}$ under visible light irradiation.

Based on the abovementioned results, a possible mechanism is put forward to explain the significantly enhanced photocatalytic activity over the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ photocatalyst. As reported in previous studies, the work function of ZnO and In_2O_3 is 5.3 eV, 5.0 eV, whereas the work function of Ag is about 4.7 eV.^{49–51} After contact of In_2O_3 , ZnO, and Ag, the Fermi energy level of ZnO becomes lower than that of In_2O_3 and Ag, and the electron transfers from In_2O_3 and Ag with higher Fermi level to ZnO until the united new Fermi energy level (E_f) is formed (Fig. 9(a)).^{26,52}

For the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ system, the highest photocatalytic efficiency can be attributed to the good interface charge transfer process in the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ heterojunction composites and the high crystallinity of ZnO, In_2O_3 and Ag; a possible schematic is presented in Fig. 9(b). It is well known that ZnO and In_2O_3 are n-type semiconductors and have staggered band offsets. Hence, a type II heterojunction will be formed between In_2O_3 and ZnO after contact. When $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ is irradiated by visible-light, the VB electrons of the In_2O_3 can be excited and migrate to the CB, leaving holes on the VB; the excited electrons will then transfer from the CB of the In_2O_3 to the CB of ZnO. Because the energy level of the CB for semiconductor ZnO is higher than the newly formed Fermi energy level E_f , subsequently, the electrons in the CB of ZnO then can further transfer to Ag. Therefore, Ag nanowires served as a terminal electron acceptor, thus prolonging the photogenerated electrons lifetime and facilitating the charge separation in the whole photocatalytic system. The high crystallinity and intimate interface contact between In_2O_3 ,

and ZnO benefits the separation of photo-excited electrons and holes, hence enhancing the photocatalytic activity of the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites.^{53,54} On the other hand, the SPR effect introduced by the Ag nanoparticles may also play a role in enhanced photocatalytic activities. Surface plasmon excitations are generated and partially converted into energetic electrons under visible-light irradiation.^{34,55} The energetic electrons are able to overcome the Schottky barrier at the interface of Ag–ZnO and transfer from Ag to the CB of ZnO due to its strong electron oscillating collectively upon SPR excitation.^{56,57}

Subsequently, electron acceptors, such as adsorbed O_2 , can easily trap photoelectrons to yield superoxide radical anion ($\cdot\text{O}_2^-$) species. Degradation of organic contaminant subsequently takes place through $\cdot\text{O}_2^-$ radicals attacking the organic molecules. Moreover, the photo-generated holes in the valence band of In_2O_3 would transfer to the photocatalyst surface and directly oxidize the organic pollutants, resulting in obviously improved photocatalytic activity.^{58,59}

4. Conclusions

In summary, an $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary photocatalyst was successfully synthesized by a co-precipitation route. SEM investigation reveals that Ag nanomaterials are encapsulated by $\text{In}_2\text{O}_3/\text{ZnO}$, where large quantities of In_2O_3 NPs are inlaid in the ZnO shell. Compared to those of pure ZnO and $\text{In}_2\text{O}_3/\text{ZnO}$, the photo responsive range is extended and PL emission intensity is significantly decreased for $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ ternary composite; and the ternary photocatalyst $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composite shows the highest visible-light photocatalytic activity for the degradation of MO and 4-NP. The photocatalytic mechanism analysis reveals that the introduction of Ag plays an essential role in improving the photocatalytic activity, owing to the enlarged light absorption region and strong localization of plasmonic near-field effects; moreover, In_2O_3 provides a broad light absorption region and effectively enhances electron transfer at interfaces by the formation of a type II heterojunction. Therefore, there is a synergetic effect among ZnO, In_2O_3 , and Ag nanowires in the investigated composites, which is favorable for the visible light photocatalytic activity of the $\text{In}_2\text{O}_3/\text{ZnO}@Ag$ composites.



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